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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Byung Jin AHN, et al.

Serial No.: 10/750,850

Group Art Unit: 2818

Filed: January 5, 2004

Examiner: Nguyen, Dao H

For: FLASH MEMORY CELL AND METHOD OF MANUFACTURING THE SAME, AND

PROGRAMMING/ERASING/READING METHOD IN THE FLASH MEMORY CELL

PETITION FOR EXTENSION OF TIME

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

December 13, 2004

Sir:

Applicant hereby petitions that an extension of the term necessary to render timely the filing of a response in the above-identified application be granted. Costs under 37 CFR 1.17(a)-(d) for such extension(s) and/or any other fee due with this response, not fully covered by the enclosed check in the amount of \$120.00, may be charged to our Deposit Account No.50-3226.

Respectfully submitted,

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